



# **PRODUCT RELIABILITY REPORT**

**Product: MPQ2177-AEC1**

**Reliability Department  
Monolithic Power Systems  
79 Great Oaks Boulevard  
San Jose, CA 95119  
Tel: 408-826-0600  
Fax: 408-826-0601**



## 1. Device Information

|                     |                         |
|---------------------|-------------------------|
| Product:            | MPQ2177-AEC1            |
| Package:            | 8-PIN FC-QFN(1.5mm×2mm) |
| Process Technology: | BCD                     |
| Report Date:        | 04/16/2021              |

## 2. Summary of Test Results

| <b>TEST GROUP A – ACCELERATED ENVIRONMENT STRESS TESTS</b>     |          |                                                                                 |                               |                                |                |
|----------------------------------------------------------------|----------|---------------------------------------------------------------------------------|-------------------------------|--------------------------------|----------------|
| <b>Test</b>                                                    | <b>#</b> | <b>Test Condition</b>                                                           | <b>Lot# or Date Code</b>      | <b>Test Results (S.S./Rej)</b> | <b>Comment</b> |
| Preconditioning, prior to THB/HAST, AC/UHAST, TC, HTSL and PTC | A1       | J-STD-020<br>Reflow: Tp>=260°C,<br>tp>=30sec, 3×reflows                         | 1921<br>1941<br>1946          | 308/0<br>308/0<br>308/0        | MSL=1          |
| Temperature Humidity Bias Life Test (THB)                      | A2       | JESD22-A101,<br>@85°C/85%RH static bias at Vinmax for 1000 hours or equivalent. | 1921<br>1941<br>1946          | 77/0<br>77/0<br>77/0           |                |
| Unbiased Autoclave (AC)                                        | A3       | JESD22-A102,<br>@121°C/100%RH for 168 hours or equivalent.                      | 1921<br>1941<br>1946          | 77/0<br>77/0<br>77/0           |                |
| Temperature Cycling (TC)                                       | A4       | JESD22-A104, from -65°C to 150°C for 1000 cycles or equivalent.                 | 1921<br>1941<br>1946          | 77/0<br>77/0<br>77/0           |                |
| Power Temperature Cycling (PTC)                                | A5       | JESD22-A105, from -40°C to 125°C for 1000 cycles.                               | SJD0967                       | 45/0                           |                |
| High Temperature Storage Life (HTSL)                           | A6       | JESD22-A103, @175°C for 1000 hours.                                             | 1921<br>1941<br>1946          | 77/0<br>77/0<br>77/0           |                |
| <b>TEST GROUP B – ACCELERATED LIFETIME SIMULATION TESTS</b>    |          |                                                                                 |                               |                                |                |
| <b>Test</b>                                                    | <b>#</b> | <b>Test Condition</b>                                                           | <b>Lot# or Date Code</b>      | <b>Test Results (S.S./Rej)</b> | <b>Comment</b> |
| High Temperature Operating Life (HTOL)                         | B1       | JESD22-A108,<br>@Tj=150°C for 1000 hours or equivalent                          | SJ14326<br>SJD0967<br>SI33348 | 77/0<br>77/0<br>77/0           |                |

| Early Life Failure Rate (ELFR)                          | B2 | AEC-Q100-008,<br>@Tj=150°C for 48 hours,<br>or equivalent                                        | SI33348<br>SJ04552<br>SJD0967 | 800/0<br>800/0<br>800/0 |                                       |
|---------------------------------------------------------|----|--------------------------------------------------------------------------------------------------|-------------------------------|-------------------------|---------------------------------------|
| <b>TEST GROUP C – PACKAGE ASSEMBLY INTEGRITY TESTS</b>  |    |                                                                                                  |                               |                         |                                       |
| Test                                                    | #  | Test Condition                                                                                   | Lot# or Date Code             | Test Results (S.S./Rej) | Comment                               |
| Solderability (SD)                                      | C3 | JESD22-B102<br>J-STD-002D<br>>95% lead coverage                                                  | 1921                          | 15/0                    |                                       |
| Physical Dimensions (PD)                                | C4 | JESD22-B100/108<br>AEC-Q003<br>C <sub>PK</sub> >1.67                                             | 1921<br>1941<br>1946          | 30/0<br>30/0<br>30/0    |                                       |
| Bump Shear Test (BST)                                   | C7 | JESD22-B117<br>AEC-Q003<br>C <sub>PK</sub> >1.67<br>20 bumps/pillars from a minimum of 5 devices | 1921                          | 5/0                     |                                       |
| <b>TEST GROUP D – DIE FABRICATION RELIABILITY TESTS</b> |    |                                                                                                  |                               |                         |                                       |
| Test                                                    | #  | Test Condition                                                                                   | Lot# or Date Code             | Test Results (S.S./Rej) | Comment                               |
| Electromigration (EM)                                   | D1 | JESD61<br>JP001                                                                                  | —                             | —                       | Pass                                  |
| Time Dependent Dielectric Breakdown (TDDB)              | D2 | JESD36<br>JP001                                                                                  | —                             | —                       | Pass                                  |
| Hot Carrier Injection (HCI)                             | D3 | JESD60 and 28<br>JP001                                                                           | —                             | —                       | Pass                                  |
| Negative Bias Temperature Instability (NBTI)            | D4 | JESD90<br>JP001                                                                                  | —                             | —                       | Pass                                  |
| Stress Migration (SM)                                   | D5 | JESD61,87 and 202<br>JP001                                                                       | —                             | —                       | Pass                                  |
| <b>TEST GROUP E – ELECTRICAL VERIFICATION TESTS</b>     |    |                                                                                                  |                               |                         |                                       |
| Test                                                    | #  | Test Condition                                                                                   | Lot# or Date Code             | Test Results (S.S./Rej) | Comment                               |
| ESD: Human Body Model (HBM)                             | E2 | AEC-Q100-002                                                                                     | HP7983                        | 3/0                     | >2000V                                |
| ESD: Device Charged Model (CDM)                         | E3 | AEC-Q100-011                                                                                     | HP7983                        | 3/0                     | >750V                                 |
| Latch-up                                                | E4 | AEC-Q100-004                                                                                     | HP7983                        | 6/0                     | >+/-100mA &<br>>1.5V <sub>ccmax</sub> |

## **5. Failure Rate Calculation**

|                           |                          |
|---------------------------|--------------------------|
| Sample Size:              | 4250                     |
| Rejects:                  | 0                        |
| Activation Energy (eV):   | 0.7                      |
| Equivalent Device Hours:  | $3.32 \times 10^8$ Hours |
| Failure Rate (FIT@60%CL): | 2.8 FIT                  |
| MTBF (years):             | 41,358 Years             |

## **Revision / Update History**

| <u>Revision</u> | <u>Reason for Change</u> | <u>Date</u> | <u>Rel Engineer</u> |
|-----------------|--------------------------|-------------|---------------------|
| 1.0             | Initial release          | April 2021  | Ramon Lei           |

## **Appendix: Description of Reliability Test and Failure Rate Calculation**

### **High Temperature Operating Life Test**

**Purpose:** This test is a worst-case life test that checks the integrity of the product. The high temperature testing is used for acceleration of any potential failures over time. The calculation for failure rate (FIT) using the operating ambient temperature is done using the Arrhenius equation.

**Condition:** T<sub>j</sub>=150°C @ Vinmax

**Pass Criteria:** All units must pass the min/max limits of the datasheet.

### **ESD Test**

**Purpose:** The purpose of the ESD test is to guarantee that the device can withstand electrostatic voltages during handling.

**Condition:** Human Body Model and Charged Device Model

**Pass Criteria:** ESD Testing on every pin. The device must be fully functional after testing and pass the min/max limits in the datasheet.

### **IC Latch-Up Test**

**Purpose:** The purpose of this specification is to establish a method for determining IC latch-up characteristics and to define latch-up failure criteria. Latch-up characteristics are extremely important in determining product reliability and minimizing No Trouble Found (NTF) and Electrical Overstress (EOS) failures due to latch-up.

**Condition:** Voltage and current injection

**Pass criteria:** All pins with the exception of “no connect” pins and timing related pins, shall be latch-up tested. The device must be fully functional after testing and pass the min/max limits in the datasheet.

### **Moisture/Reflow Sensitivity Classification for Nonhermetic Solid State Surface Mount Devices**

**Purpose:** The purpose of this standard is to identify the classification level of nonhermetic solid state surface mount devices (SMDs) that are sensitive to moisture-induced stress so that they can be properly packaged, stored, and handled to avoid damage during assembly solder reflow attachment and/or repair operations.

**Condition:** Bake + moisture sock + 3X reflow at 260°C

**Pass criteria:** All units must pass the min/max limits of the datasheet

### **Accelerated Moisture Resistance- Unbiased Autoclave**

**Purpose:** To check the performance of the device in humid environments. This test checks the integrity of the passivation, poor metal to plastic seal and contamination level during assembly and material compatibility.

**Condition:** 121°C/15psig/100% RH (no bias)

**Pass Criteria:** All units must pass min/max limits of the datasheet

### **Temperature Cycle Test**

**Purpose:** This test is used to evaluate the die attach integrity and bond integrity. This is similar to the Thermal Shock test, but can generate different failure modes due to the longer dwell time and gradual temperature change.

**Condition:** -65°C to 150°C

**Pass Criteria:** All units must pass min/max limits of the datasheet

### **Steady State Temperature Humidity Bias Life Test**

**Purpose:** This is to check the performance of the device in humid environments. This test checks the integrity of the passivation, poor metal to plastic seal and contamination level during assembly and material compatibility.

**Condition:** 85%RH at 85°C with Vin=Vinmax

**Pass Criteria:** All units must pass min/max limits of the datasheet

**Highly Accelerated Temperature and Humidity Stress Test**

- Purpose:** This is an equivalent test to Steady State Temperature Humidity Bias Life test with different (higher) temperature stress condition.
- Condition:** 85%RH at 130°C with Vin=Vinmax
- Pass Criteria:** All units must pass min/max limits of the datasheet

**Failure Rate Calculation**

The failure rate is gauged by a Failures-In-Time (FIT) based upon accelerated stress data. The unit for FIT is failure per billion device hour.

$$FIT\ Rate = \frac{(\chi^2/2) \times 10^9}{EDH}$$

Where

- χ<sup>2</sup> (Chi-Squared) is the goodness-of-fit test statistic at a specified level of confidence;
- EDH= Equivalent Device Hours = AF × (Life test sample size) × (test duration);
- AF= Acceleration Factor.

High Temperature Operating Life (HTOL) test is usually done under acceleration of temperature and voltage. The total number of failures from the stress test determines the chi-squared factor.

$$AF = AF_T \times AF_V$$

The Temperature Acceleration Factor AF<sub>T</sub>:

$$AF_T = \exp\left(\frac{E_a}{K} \left( \frac{1}{T_{J(USE)}} - \frac{1}{T_{J(STRESS)}} \right)\right)$$

- T<sub>JUSE</sub> = Junction temp under typical operating conditions;
- T<sub>JSTRESS</sub> = Junction temp under accelerated test conditions;
- E<sub>a</sub> is Activation energy=0.7eV;
- K=Boltzmann’s constant=8.62×10<sup>-5</sup> eV/K.

The voltage Acceleration Factor AF<sub>V</sub>:

$$AF_V = e^{\beta \times [V_{STRESS} - V_{USE}]}$$

- V<sub>USE</sub> = Gate voltage under typical operating conditions;
- V<sub>STRESS</sub> = Gate voltage under accelerated test conditions;
- β = Voltage acceleration factor (in 1/Volts) and specified by technology.
- Note: For calculation in the report, AF<sub>V</sub> = 1 for simplicity.

MTBF (Mean Time Between Failure) equals to 10<sup>9</sup>/FIT (in hours).